

AMENDMENTS TO THE SPECIFICATION

Please replace the present title with the following amended title:

COMPOUND SEMICONDUCTOR LIGHT-EMITTING DEVICE AND
PRODUCTION METHOD THEREOF WITH AN AlGaInP LIGHT-EMITTING LAYER
FORMED WITHIN

Please replace the paragraph on page 1 of the specification under the heading
“CROSS-REFERENCE TO RELATED APPLICATION” with the following amended
paragraph:

Priority is claimed to Japanese application No. 2004-095145, filed March 29, 2004,
which are incorporated herein by reference. This application also claims the benefit pursuant to
35 U.S.C. § 119(e)(1) is a 371 of PCT/JP2005/006520 filed March 28, 2005, claiming benefit of
U.S. Provisional Applications, No. Application No. 60/559,429 filed April 6, 2004. Priority to
Japanese Application No. 2004-095145 filed March 29, 2004 is also claimed, incorporated
herein by reference.